# onsemi

# **PNP RF Transistor**

## **MMBTH81**

This device is designed for general RF amplifier and mixer applications to 250 MHz with collector currents in the 1.0 mA to 30 mA range. Sourced from Process 75.

#### Features

- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Units
Collector – Emitter Voltage	V <sub>CEO</sub>	20	V
Collector – Base Voltage	V <sub>CBO</sub>	20	V
Emitter – Base Voltage	V <sub>EBO</sub>	3.0	V
Collector Current – Continuous	Ι <sub>C</sub>	50	mA
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

THERMAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

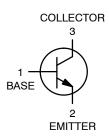
Characteristic	Symbol	Max	Unit
Total Device Dissipation Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

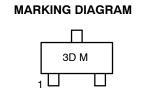
1. Device mounted on FR-4 PCB  $1.6 \times 1.6 \times 0.06$  in.

2. These ratings are based on a maximum junction temperature of 150°C.

- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
- 4. All voltages (V) and currents (A) are negative polarity for PNP transistors.







3D = Specific Device Code M = Date Code\*

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

### MMBTH81

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARA	CTERISTICS	•			
V <sub>(BR)CEO</sub>	Collector – Emitter Breakdown Voltage (Note 5)	I <sub>C</sub> = 1.0 mA, I <sub>B</sub> = 0	20		V
V <sub>(BR)CBO</sub>	Collector – Base Breakdown Voltage	$I_{C} = 10 \ \mu A, I_{E} = 0$	20		V
V <sub>(BR)EBO</sub>	Emitter – Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	3.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0$		100	nA
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 2.0 \text{ V}, I_C = 0$		100	nA
ON CHARAC	TERISTICS				
h <sub>FE</sub>	DC Current Gain	$I_{C} = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$	60		
V <sub>CE(sat)</sub>	Collector – Emitter Saturation Voltage	I <sub>C</sub> = 5.0 mA, I <sub>B</sub> = 0.5 mA		0.5	V
V <sub>BE(sat)</sub>	Base – Emitter Saturation Voltage	$I_{C} = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$		0.9	V
SMALL SIG	NAL CHARACTERISTICS				
f <sub>T</sub>	Current Gain – Bandwidth Product	$I_{C} = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}, \text{ f} = 100 \text{ MHz}$	600		MHz
C <sub>cb</sub>	Collector-Base Capacitance	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz		0.85	pF

C<sub>ce</sub> Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

 $V_{CB}=10 \text{ V}, \text{ I}_{B}=0, \text{ }f=1.0 \text{ MHz}$ 

0.65

pF

5. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2.0%.

Collector Emitter Capacitance

#### SPICE MODEL

PNP(Is=10f Xti=3 Eg=1.11 Vaf=100 Bf=133.8 Ise=1.678p Ne=2.159 Ikf=.1658 Nk=.901 Xtb=1.5 Var=100 Br=1 Isc=9.519n Nc=3.88 Ikr=5.813 Rc=7.838 Cjc=2.81p Mjc=.1615 Vjc=.8282 Fc=.5 Cje=2.695p Mje=.3214 Vje=.7026 Tr=11.32n Tf=97.83p Itf=69.29 Xtf=599u Vtf=10)

#### **ORDERING INFORMATION**

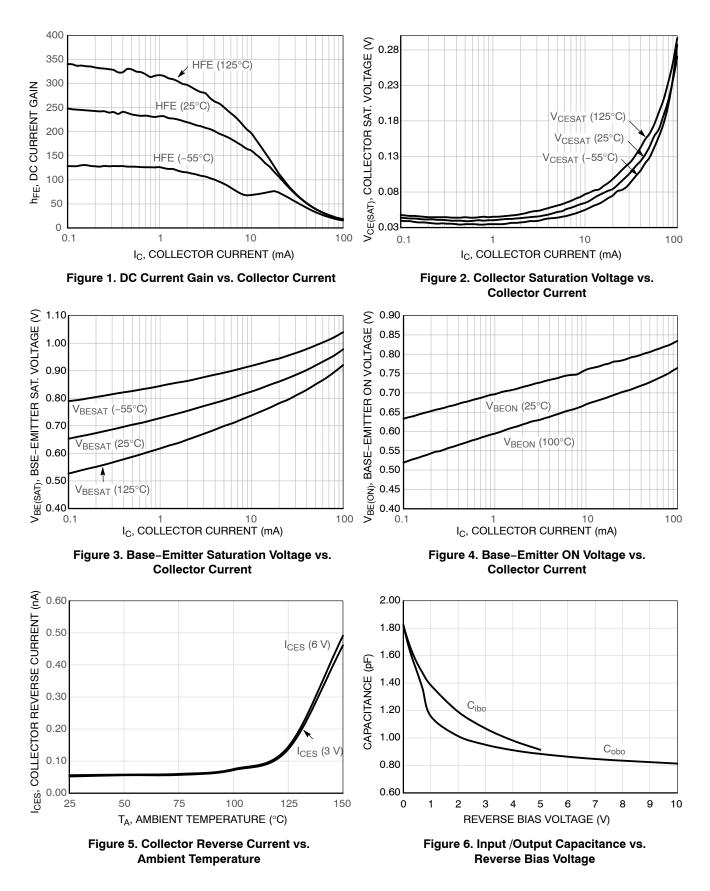
Device	Specific Marking Code	Package	Shipping <sup>†</sup>
NSVMMBTH81LT1G*	3D	SOT-23 (Pb-Free)	3,000 / Tape & Reel
NSVMMBTH81LT3G*	3D	SOT-23 (Pb-Free)	10,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

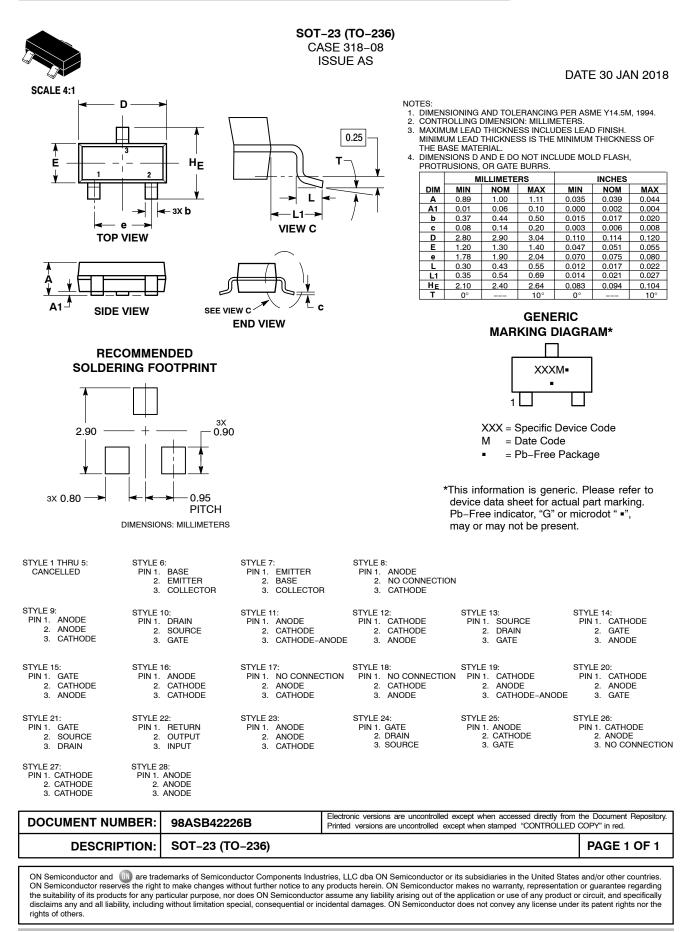
\*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

#### MMBTH81

#### **TYPICAL CHARACTERISTICS**







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